

Description

The NTD4404N1G uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

D S S

TO-252-2L

General Features

 $V_{DS} = 30V I_{D} = 100 A$

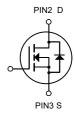
 $R_{DS(ON)} < 5m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
NTD4404N1G	TO-252-2L	HXY MOSFET	2500

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating		Units
Vos	Drain- Source Voltage	30		V
Vgs	Gate-Source Voltage	±20		V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	100		А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	57		Α
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	27 17		А
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	23	14.5	А
Ірм	Pulsed Drain Current ²	160		А
EAS	Single Pulse Avalanche Energy ³	115.2		mJ
las	Avalanche Current	48		А
P _D @T _C =25°C	Total Power Dissipation ⁴	53		W
P _D @T _A =25°C	Total Power Dissipation ⁴	6	2.4	W
Тѕтс	Storage Temperature Range	-55 to 175		°C
TJ	Operating Junction Temperature Range	-55 to 175		°C
R _θ JA	Thermal Resistance Junction-ambient (Steady State)¹	62		°C/W
Reja	Thermal Resistance Junction-Ambient ¹ (t ≤10s)	25		°C/W
R _θ JC	Thermal Resistance Junction-Case ¹	2.8		°C/W



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V
△BVɒss/△Tɹ	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA		0.028		V/°C
	Static Drain-Source On-	V _{GS} =10V , I _D =30A		3.8	5.5	
RDS(ON)	Resistance ²	V _{GS} =4.5V , I _D =15A		7.5	9	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.0	1.5	2.5	V
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	33 33 7 3 3 3 3		-6.16		mV/°C
		V _{DS} =24V , V _{GS} =0V ,			1	
Ipss	Drain-Source Leakage Current	T _J =25°C				uA
.500	Diani-Source Leakage Guiletti	V _{DS} =24V , V _{GS} =0V , T _J =55°C			5	
Igss	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =30A		22		S
R _g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.7	3.4	Ω
Q_g	Total Gate Charge (4.5V)			20		
Qgs	Gate-Source Charge	V _{DS} =15V , V _{GS} =4.5V ,		7.6		nC
Q _{gd}	Gate-Drain Charge			7.2		
Td(on)	Turn-On Delay Time			7.8		
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V ,		15		ns
Td(off)	Turn-Off Delay Time	— R _G =3.3Ω — I _D =15A		37.3		
Tf	Fall Time			10.6		
C _{iss}	Input Capacitance			2295		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		267		pF
Crss	Reverse Transfer Capacitance	1- 11VII 12		210		
Is	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force			80	Α
Ism	Pulsed Source Current ^{2,5}	Current			160	Α
Vsp	Diode Forward Voltage ²	V _{GS} =0V, I _S =1A , T _J =25°C			1	V
t _{rr}	Reverse Recovery Time	IF=30A , dI/dt=100A/μs ,		14		nS
Qrr	Reverse Recovery Charge			5		nC

Note:

^{1.}The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

^{2.} The data tested by pulsed , pulse width . The EAS data shows Max. rating .

^{3.}The test cond ≤ 300us , duty cycle ition is $V_{DD=25}\!\!\le\!\!V,\!V_{GS}$ 2% =10V,L=0.1mH,I_As=53.8A

^{4.}The power dissipation is limited by 175°C junction temperature

^{5.} The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.



Typical Characteristics

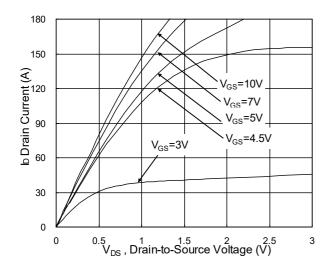


Fig.1 Typical Output Characteristics

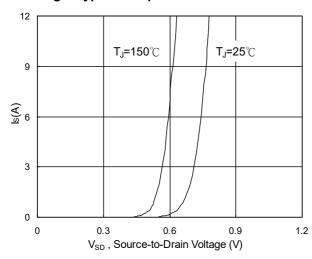


Fig.3 Forward Characteristics of Reverse

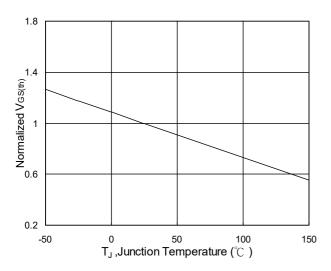


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

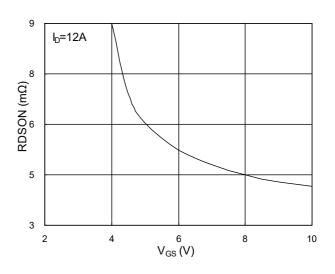


Fig.2 On-Resistance vs. G-S Voltage

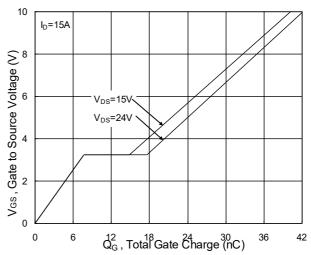


Fig.4 Gate-Charge Characteristics

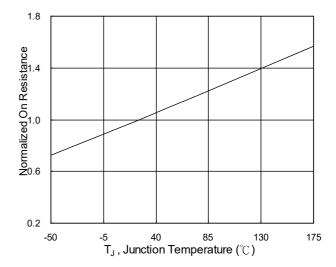
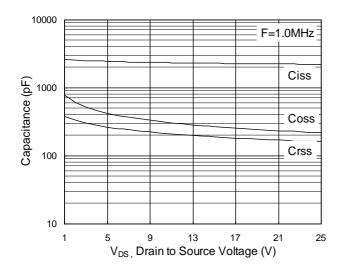


Fig.6 Normalized R_{DSON} vs. T_J



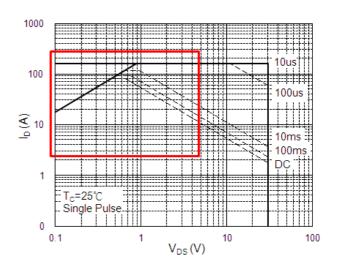


Fig.7 Capacitance

Fig.8 Safe Operating Area

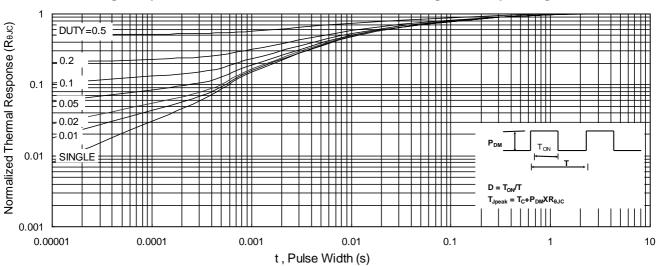


Fig.9 Normalized Maximum Transient Thermal Impedance

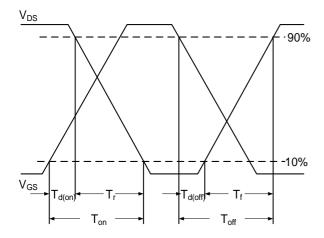


Fig.10 Switching Time Waveform

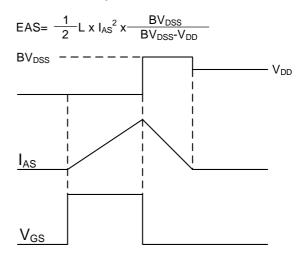
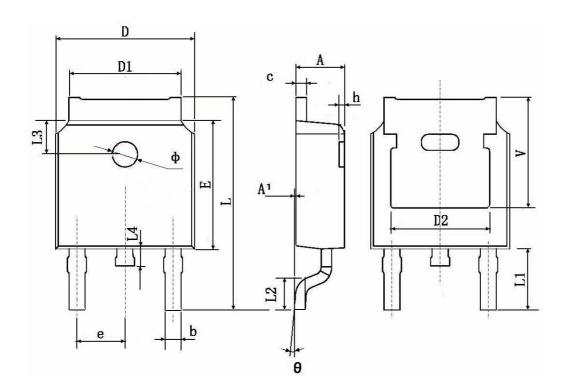


Fig.11 Unclamped Inductive Switching Waveform



TO-252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483	0.483 TYP.		TYP.	
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	5.350 TYP. 0.211 TYP.		TYP.	



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